

Ordering Information

| Device | Device Marking | Package |
| :---: | :---: | :---: |
| MC13851EP | 851 | MLPD-8 |

## 1 Introduction

The MC13851 is a cost-effective, high IP3 LNA with low noise figure. This is the smaller leadless package version of the MC13821 device. The MC13851 includes an integrated bypass switch to preserve high input intercept performance in variable signal strength environments and boosts dynamic range. On-chip bias circuitry offers low system cost. The input and output match are external to allow maximum design flexibility. An external resistor is used to set device current which allows balancing required linearity with low current consumption. Gain is optimized for applications greater than 1000 MHz . The MC13851 is fabricated with the advanced RF BiCMOS process using the eSiGe:C module and is available in the $2 \times 2 \mathrm{~mm}$ MLPD- 8 leadless package, offering a small, low height, easy-to-solder solution for applications with tight printed circuit board placement requirements.

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### 1.1 Features

The MC13851 is intended for applications from 1000 MHz to 2500 MHz and the MC13852 is for applications less than 1000 MHz .

- Gain: 18.7 dB (typical) at 1960 MHz and 17.7 dB (typical) at 2140 MHz
- Output third order intercept point (OIP3): 16 dBm at 1960 MHz and 17 dBm (typical) dBm at 2140 MHz
- Noise Figure (NF): 1.37 dB (typical) at 1960 MHz and 1.46 dB at 2140 MHz
- Output 1 dB compression point (P1dB): 8 dBm (typical) at 1960 MHz and 8 dBm (typical) at 2140 MHz
- IP3 Boost Circuitry from Freescale
- Bypass mode has return losses comparable to active mode, for use in systems with filters and duplexers
- Bypass mode improves dynamic range in variable signal strength environments
- Integrated logic-controlled standby mode with current drain < 1uA
- Total supply current variable from $2.5 \mathrm{~mA}-5 \mathrm{~mA}$ using an external bias resistor
- In a receiver system with $20 \%$ active mode and $80 \%$ bypass mode, the average current drain is $<0.6$ mA
- On-chip bias sets the bias point
- Bias stabilized for device and temperature variations
- MLPD-8 leadless package with low parasitics
- $1575 \mathrm{MHz}, 1960 \mathrm{MHz}, 2140 \mathrm{MHz}$ and 2500 MHz application circuit evaluation boards with characterization data are available
- Available in tape and reel packaging


### 1.2 Applications

Ideal for use in any RF product that operates between 1000 MHz and 2.5 GHz , and may be applied in:

- Buffer amplifiers
- Mixers
- IF amplifiers
- Voltage controlled oscillators (VCOs)
- Use with transceivers requiring external LNAs
- Smart metering
- Mobile-Cellular front end LNA, GPS, two-way radios
- Consumer—WLAN, $802.11 \mathrm{~b} / \mathrm{g}$
- Auto-GPS, active antenna, wireless security
- Low current drain/long standby time for extended battery life applications

Figure 1 shows a simplified block diagram of the MC13851 with the pinouts and location of the Pin 1 designator on the package.


Figure 1. Functional Block Diagram

## 2 Electrical Specifications

Table 1. lists the maximum ratings for the device.
Table 1. Maximum Ratings ( $\mathrm{TA}=25^{\circ} \mathrm{C}$, unless otherwise noted)

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Supply voltage | Vcc | 3.3 | Vdc |
| Storage temperature range | $\mathrm{T}_{\text {stg }}$ | $-65-150$ | ${ }^{\circ} \mathrm{C}$ |
| Operating ambient temperature range | $\mathrm{T}_{\mathrm{A}}$ | $-30-85$ | ${ }^{\circ} \mathrm{C}$ |
| RF input power | $\mathrm{P}_{\mathrm{RF}}$ | 10 | dBm |
| Power dissipation | Pdis | 100 | mW |
| Thermal resistance, junction to case | $\mathrm{R}_{\text {thetaJC }}$ | 24 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal resistance, junction to ambient, 4 layer board | $\mathrm{R}_{\text {thetaJA }}$ | 90 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Note: Maximum ratings

1. Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the recommended Operating Conditions and Electrical Characteristics tables.
2. ESD (electrostatic discharge) immunity meets Human Body Model (HBM) $\leq 200 \mathrm{~V}$. Charge Device Model (CDM) $\leq 450 \mathrm{~V}$, and

Machine Model (MM) $\leq 50 \mathrm{~V}$
Table 2 lists the recommended operating conditions.
Table 2. Recommended Operating Conditions

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| RF frequency range | $\mathrm{f}_{\mathrm{RF}}$ | 1000 | - | 2500 | MHz |
| Supply voltage | $\mathrm{V}_{\mathrm{CC}}$ | 2.3 | 2.75 | 3 | V |

Table 2. Recommended Operating Conditions (continued)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Logic voltage |  |  |  |  |  |
| Input high voltage | - | 1.25 | 1.8 | $\mathrm{V}_{\mathrm{CC}}$ | Vdc |
| Input low voltage |  | 0 | 0 | 0.80 | Vdc |

Table 3 shows the use of the Gain and Enable pins to select Active mode (High Gain), Bypass mode (Low Gain) or Standby mode (Disable) operation.

Table 3. Truth Table

| Pin Function | Pin Name | Enable |  | Disable |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Low Gain | High Gain | Low Gain | High Gain |
| Logic Circuit Bias Vcc | Vcc | 1 | 1 | 1 | 1 |
| Toggles Gain Mode (Active or Bypass) | Gain | 0 | 1 | 0 | 1 |
| Toggles LNA On/Off | Enable | 1 | 1 | 0 | 0 |

Notes:

1. Logic state 1 equals Vcc voltage. Logic state of 0 equals ground potential.
2. Vcc is inductively coupled to LNA Out pin and Vcc pin
3. Minimum logic state 1 for enable and gain pins is 1.25 V
4. Maximum logic state 0 for enable and gain pins is 0.8 V

Table 4 lists the electrical characteristics associated with noise performance measured in a $50 \Omega$ system. Additional noise parameters are listed in Table 15 and Table 16. Also listed are the typical Icc and RF turn on times for the device. Information and details on the boards are shown in Section 4, "Printed Circuit and Bill of Materials."

Table 4. Electrical Characteristics (Vcc $=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Gain | \|S211| ${ }^{2}$ |  |  |  | dB |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 17.4 | 18.9 | - |  |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 14.5 | 16 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 16.4 | 17.9 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 14.9 | 16.4 | - |  |
| Maximum Stable Gain and/or Maximum Available Gain [Note1] | MSG, MAG |  |  |  | dB |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 21.1 | 22.6 | - |  |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 19.6 | 21.1 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 19 | 20.5 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 18.1 | 19.6 | - |  |
| Minimum Noise Figure | NFmin |  |  |  | dB |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | - | 0.97 | 1.3 |  |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq=2.14 GHz |  | - | 1.07 | 1.4 |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | - | 0.98 | 1.3 |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq $=2.14 \mathrm{GHz}$ |  | - | 1.1 | 1.4 |  |

Table 4. Electrical Characteristics (Vcc $=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Associated Gain at Minimum Noise Figure | Gnf |  |  |  | dB |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 20.5 | 22 | - |  |
| $\mathrm{R} 1=1.2 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 17 | 18.6 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq $=1.575 \mathrm{GHz}$ |  | 20.5 | 22 | - |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$, Freq=2.14 GHz |  | 17.5 | 19 | - |  |
| Icc and RF Turn On Time Enable trigger total time of $1.8 \mu$ second from 0 to 2.75 V |  |  |  |  |  |
| Icc rise time from 0 to $76 \%$ of final current level |  | - | 6.4 | - | $\mu \mathrm{S}$ |
| Icc rise time from 0 to $87 \%$ of final current level |  | - | 9.6 | - |  |
| RF on time from leading edge of enable trigger to RF turn-on |  | - | 1.37 | - |  |
| Note: <br> Maximum Available Gain and Maximum Stable Gain are defined $M A G=I S 21 / S 12(K \pm$ sqrt $(K 2-1)) I$, if $K>1, M S G=I S 21 / S 12 \mid$, if $K$ | K factor |  |  |  |  |

Table 5 lists the electrical characteristics measured on evaluation boards tuned for typical application frequencies when Rbias is $1.2 \mathrm{k} \Omega$. Further details on the application circuits are shown in Section 3, "Application Information"

Table 5. Electrical Characteristics Measured in Frequency Specific Tuned Circuits

$$
\left(\text { Vcc }=2.75 \mathrm{~V}, \mathrm{TA}=25^{\circ} \mathrm{C}, \text { Rbias }=1.2 \mathrm{k} \Omega \text { unless otherwise noted) }\right.
$$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1575 MHz (Refer to Figure 7) |  |  |  |  |  |
| Frequency | f | - | 1575 | - | MHz |
| Active RF Gain | G | 18.4 | 19.4 | - | dB |
| Active Noise Figure | NF | - | 1.28 | 1.6 | dB |
| Active Input Third Order Intercept Point | IIP3 | -6.5 | -5 | - | dBm |
| Active Input 1dB Compression Point | P1dBoutput | 6.3 | 7.4 | - | dBm |
| Active Current @ 2.75V, Rbias=1.2k | Icc | - | 4.8 | 5.8 | mA |
| Active Current @ 2.75V, Rbias=1.5k | Icc | - | 3.8 | 4.8 | mA |
| Active Gain | S21 | 18 | 19 | - | dB |
| Bypass RF Gain | G | -6.5 | -5.5 | - | dB |
| Bypass Noise Figure | NF | - | 6 | 7 | dB |
| Bypass Input Third Order Intercept Point | IIP3 | 24 | 25.5 | - | dBm |
| Bypass Current | - | - | 4 | 20 | $\mu \mathrm{A}$ |
| Bypass Gain | S21 | -7 | -5.5 | - | dB |
| 1960 MHz (Refer to Figure 8) |  |  |  |  |  |
| Frequency | $f$ | - | 1960 | - | MHz |
| Active RF Gain | G | 17.7 | 18.7 | - | dB |
| Active Noise Figure | NF | - | 1.37 | 1.65 | dB |
| Active Input Third Order Intercept Point | IIP3 | -4 | -2.7 | - | dBm |
| Active Input 1dB Compression Point | P1dBoutput | 6 | 8 | - | dBm |

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Table 5. Electrical Characteristics Measured in Frequency Specific Tuned Circuits (continued) (Vcc $=2.75 \mathrm{~V}, \mathrm{TA}=25^{\circ} \mathrm{C}$, Rbias $=1.2 \mathrm{k} \Omega$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Active Current @ 2.75V, Rbias=1.2k $\Omega$ | Icc | - | 4.8 | 5.8 | mA |
| Active Current @ 2.75V, Rbias=1.5k | Icc | - | 3.8 | 4.8 | mA |
| Active Gain | S 21 | 17.4 | 18.4 | - | dB |
| Bypass RF Gain | G | -6.5 | -4.9 | - | dB |
| Bypass Noise Figure | NF | - | 4.8 | 6.2 | dB |
| Bypass Input Third Order Intercept Point | IIP3 | 24.5 | 26 | - | dBm |
| Bypass Current | - | - | 4 | 20 | $\mu \mathrm{~A}$ |
| Bypass Gain | S 21 | -6.5 | -5 | - | dB |

2140 MHz (Refer to Figure 9)

| Frequency | f | - | 2140 | - | MHz |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Active RF Gain | G | 16.7 | 17.7 | - | dB |
| Active Noise Figure | NF | - | 1.46 | 1.75 | dB |
| Active Input Third Order Intercept Point | IIP 3 | -3 | -0.5 | - | dBm |
| Active Input 1dB Compression Point | P1dBoutput | 6.7 | 8 | - | dBm |
| Active Current @ 2.75V, Rbias=1.2k | Icc | - | 4.8 | 5.8 | mA |
| Active Current @ 2.75V, Rbias=1.5k | Icc | - | 3.8 | 4.8 | mA |
| Active Gain | S21 | 16.5 | 17.6 | - | dB |
| Bypass RF Gain | G | -5.8 | -4.8 | - | dB |
| Bypass Noise Figure | NF | - | 4.9 | 5.9 | dB |
| Bypass Input Third Order Intercept Point | IIP3 | 24.5 | 25.7 | - | dBm |
| Bypass Current | - | - | 4 | 20 | $\mu \mathrm{~A}$ |
| Bypass Gain | S21 | -5.7 | -4.7 | - | dB |

2400 MHz (Refer to Figure 10)

| Frequency | f | - | 2400 | - | MHz |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Active RF Gain | G | 15 | 16 | - | dB |
| Active Noise Figure | NF | - | 1.52 | 1.8 | dB |
| Active Input Third Order Intercept Point | IIP3 | -0.2 | 2 | - | dBm |
| Active Input 1dB Compression Point | P1dBoutput | 7 | 8.1 | - | dBm |
| Active Current @ 2.75V, Rbias=1.2k | Icc | - | 4.8 | 5.8 | mA |
| Active Current @ 2.75V, Rbias=1.5k | Icc | - | 3.8 | 4.8 | mA |
| Active Gain | S21 | 14.7 | 15.7 | - | dB |
| Bypass RF Gain | G | -6 | -5 | - | dB |
| Bypass Noise Figure | NF | - | 5.2 | 5.8 | dB |
| Bypass Input Third Order Intercept Point | IIP3 | 24 | 25.3 | - | dBm |
| Bypass Current | - | - | 4 | 20 | $\mu \mathrm{~A}$ |
| Bypass Gain | S21 | -5.4 | -5 | - | dB |

Figure 2 and Figure 3 show maximum stable and maximum available gain and forward insertion gain versus frequency for the packaged device in a $50 \Omega$ system using bias resistors of $1.5 \mathrm{k} \Omega$ and $1.2 \mathrm{k} \Omega$.


Figure 2. Maximum Stable/Available Gain and Forward Insertion Gain vs. Frequency (Rbias =1.5k )


Figure 3. Maximum Stable/Available Gain and Forward Insertion Gain vs. Frequency (Rbias =1.2 k )

Figure 4 and Figure 5 show minimum noise figure and associated gain versus frequency for the packaged device in a $50 \Omega$ system using bias resistors of $1.5 \mathrm{k} \Omega$ and $1.2 \mathrm{k} \Omega$.


Figure 4. Minimum Noise Figure and Associated Gain vs. Frequency (Rbias $=1.5 \mathrm{k} \Omega$ )


Figure 5. Minimum Noise Figure and Associated Gain vs. Frequency (Rbias =1.2 k )

Figure 6 shows the Icc current drain for a range of values for the external bias resistor Rbias.


Figure 6. Icc vs. Bias Resistor R1 Value

## 3 Application Information

The MC13851 LNA is designed for applications in the 1000 MHz to 2.5 GHz range. It has three different modes: High Gain, Low Gain (bypass) and standby. The LNA is programmable through the Gain and Enable pins. The logic truth table is given in Table 3. The internal bypass switch is designed for broadband applications. One of the advantages of the MC13851 is the simplification of the matching network in both bypass and amplifier modes. The bypass switch is designed so that changes of input and output return losses between bypass mode and active mode are minimized and the matching network design is simplified. In these application examples a balance is made between the competing RF performance characteristics of Icc, NF, gain, IP3 and return losses with unconditional stability. Conjugate matching is not used for the input or output. Instead, matching which achieves a trade-off in RF performance qualities is used. For a particular application or specification requirement, the matching can be changed to achieve enhanced performance of one parameter. Measurements are made at a bias of Vcc=2.75 V. Frequency spacing for IP3 measurements is 200 kHz . Non-linear measurements are made at Pin $=-30 \mathrm{dBm}$. Typical application circuits are provided for $1575 \mathrm{MHz}, 1960 \mathrm{MHz}, 2140 \mathrm{MHz}$ and 2.4 GHz applications. Typical RF performance is shown for two values of bias resistor $\mathrm{R} 1: 1.2 \mathrm{k} \Omega$ and $1.5 \mathrm{k} \Omega$. These two current drain levels offer variations in intercept point, gain and noise figure. Included with each application are the schematics and electrical performance. Section 4, "Printed Circuit and Bill of Materials" provides the evaluation board layout and Bill of Material for the circuits. Section 5, "Scattering and Noise Parameters" provides Smith charts with gain and noise circles for each application frequency.

### 3.1 1575 MHz Application

This application was designed to provide typical $\mathrm{NF}=1.28 \mathrm{~dB}$, S21 gain $=19 \mathrm{~dB}$, OIP3 $=14.5 \mathrm{dBm}$ with return losses better than -10 dB at 1575 MHz . Typical performance that can be expected from this circuit at 2.75 V is listed in Table 6 . The component values can be changed to enhance the performance of a particular parameter, but usually at the expense of another. Two values of bias resistor R1 are shown to

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demonstrate performance for different IP3 and Icc requirements. Inductor L3 provides bias to the logic circuit.

Figure 7 is the 1575 MHz application schematic with package pinouts and the circuit component topology.


Figure 7. 1575 MHz Application Schematic
Table 6 shows the electrical characteristics for the 1575 MHz evaluation board.
Table 6. Typical 1575 MHz Evaluation Board Performance
( $\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| R1=1.2 K $\Omega$ |  |  |  |  |  |
| Frequency | f | - | 1575 | - | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 18.4 | 19.4 | - |  |
| Bypass |  | -6.5 | -5.5 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 13.2 | 14.5 | - |  |
| Bypass |  | 19 | 20.3 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -6.5 | -5 | - |  |
| Bypass |  | 24 | 25.5 | - |  |
| Out Ref P1dB | P1dBout |  |  |  | dBm |
| High Gain |  | 6.3 | 7.4 | - |  |
| In Ref P1dB | P1dBin |  |  |  | dBm |
| High Gain |  | -13.3 | -12 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.28 | 1.6 |  |
| Bypass |  | - | 6 | 7 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 4.8 | 5.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.2 | - | $\mathrm{k} \Omega$ |

Table 6. Typical 1575 MHz Evaluation Board Performance (continued)

$$
\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right)
$$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -11 | -8 |  |
| Bypass |  | - | -11 | -8 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 18 | 19 | - |  |
| Bypass |  | -7 | -5.5 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -27 | -25 |  |
| Bypass |  | - | -5.7 | -4.4 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -14.9 | -9 |  |
| Bypass |  | - | -18 | -9 |  |
| R1=1.5 k $\Omega$ |  |  |  |  |  |
| Frequency | f | - | 1575 | - | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 18 | 19 | - |  |
| Bypass |  | -6.5 | -5.5 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 13.9 | 15.9 | - |  |
| Bypass |  | 19 | 20.3 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -5.5 | -3.2 | - |  |
| Bypass |  | 24 | 26 | - |  |
| Out Ref P1dB | P1dBout |  |  |  | dBm |
| High Gain |  | 6.6 | 7.6 | - |  |
| In Ref P1dB | P1dBin |  |  |  | dBm |
| High Gain |  | -13.5 | -11.5 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.27 | 1.6 |  |
| Bypass |  | - | 5.9 | 6.9 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 3.8 | 4.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.5 | - | $\mathrm{k} \Omega$ |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -10.6 | -8.6 |  |
| Bypass |  | - | -11.5 | -10 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 17.9 | 18.9 | - |  |
| Bypass |  | -6.5 | -5.5 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -25.9 | -24.5 |  |
| Bypass |  | - | -5.6 | -4.6 |  |

Table 6. Typical 1575 MHz Evaluation Board Performance (continued)

$$
\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right)
$$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -13 | -9 |  |
| Bypass |  | - | -18 | -12 |  |

### 3.2 1960 MHz Application

These application circuits are designed to demonstrate performance at 1960 MHz . Typical results of $\mathrm{NF}=1.4 \mathrm{~dB}, \mathrm{~S} 21$ gain $>18 \mathrm{~dB}$ and OIP3 of 16 dBm . Two values of bias resistor R1 are shown to demonstrate performance for different IP3 and Icc requirements. Resistor R3 is used to de-Q output inductor L2 and adjust gain and return losses. Inductor L3 provides bias to the logic circuit. Reducing R3 lowers gain and improves return losses. Typical performance that can be expected from this circuit at 2.75 V is listed in Table 7.
Figure 8 is the 1960 MHz application schematic with package pinouts and the circuit component topology.


Figure 8. 1960 MHz Application Schematic
Table 7 shows the electrical characteristics for the 1960 MHz evaluation board.
Table 7. Typical 1960 MHz Evaluation Board Performance ( $\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| R1=1.2 K $\Omega$ |  |  |  |  |  |
| Frequency | f | - | 1960 | - | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 17.7 | 18.7 | - |  |
| Bypass |  | -6.5 | -4.9 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 14 | 16 | - |  |
| Bypass |  | 19.2 | 20.9 | - |  |

Table 7. Typical 1960 MHz Evaluation Board Performance (continued) ( $\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -4 | -2.7 | - |  |
| Bypass |  | 24.5 | 26 | - |  |
| Out Ref P1dB | P1dBout |  |  |  | dBm |
| High Gain |  | 6 | 8 | - |  |
| In Ref P1dB | P1dBin |  |  |  | dBm |
| High Gain |  | -13 | -10.5 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.37 | 1.65 |  |
| Bypass |  | - | 4.8 | 6.2 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 4.8 | 5.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.2 | - | k ת |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -10 | -7 |  |
| Bypass |  | - | -11 | -8 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 17.4 | 18.4 | - |  |
| Bypass |  | -6.5 | -5 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -25 | -23.5 |  |
| Bypass |  | - | -4.8 | -3 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -14 | -8 |  |
| Bypass |  | - | -14.8 | -10 |  |
| $\mathrm{R} 1=1.5 \mathrm{k} \Omega$ |  |  |  |  |  |
| Frequency | f | - | 1960 | - | MHz |
| RF Gain | G |  |  |  |  |
| High Gain |  | 17.5 | 18.5 | - | dB |
| Bypass |  | -6.8 | -5 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 16.1 | 17.1 | - |  |
| Bypass |  | 19.1 | 20.9 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -3 | -1.5 | - |  |
| Bypass |  | 24.5 | 26 | - |  |

Table 7. Typical 1960 MHz Evaluation Board Performance (continued) ( $\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Out Ref P1dB | P1dBout |  |  |  | dBm |
| High Gain |  | 5.6 | 8 | - |  |
| In Ref P1dB | P1dBin |  |  |  | dBm |
| High Gain |  | -13 | -10.5 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.35 | 1.65 |  |
| Bypass |  | - | 4.9 | 6.2 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 3.8 | 4.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.5 | - | $\mathrm{k} \Omega$ |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -9 | -6.5 |  |
| Bypass |  | - | -11 | -8 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 17 | 18 | - |  |
| Bypass |  | -6.5 | -5 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -24.5 | -22.5 |  |
| Bypass |  | - | -4.5 | -4 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -12.5 | -7 |  |
| Bypass |  | - | -15 | -10 |  |

### 3.3 2140 MHz Application

These application circuits demonstrate performance at 2140 MHz . Matching component values can be changed to enhance a particular parameter. Typical performance expected from this circuit at 2.75 V Vcc is listed in Table 8. Two values of bias resistor R1 are shown to demonstrate performance for different IP3 and Icc requirements. The same matching topology is used on each of the application circuits, with a highpass match on the output and a simple inductor-capacitor network on the LNA input. Resistor R3 is used to de-Q output inductor L2 and adjust gain and return losses. Lowering the value of R3 lowers gain and improves return losses.

Figure 9 is the 2140 MHz application schematic with package pinouts and the circuit component topology.


Figure 9. 2140 MHz Application Schematic
Table 8 shows the electrical characteristics for the 2140 MHz evaluation board.
Table 8. Typical 2140 MHz Evaluation Board Performance
$\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| R1=1.2 K $\Omega$ (Refer to Figure 9) |  |  |  |  |  |
| Frequency | f | - | 2140 | - | MHz |
| RF Gain | G |  |  |  |  |
| High Gain |  | 16.7 | 17.7 | - | dB |
| Bypass |  | -5.8 | -4.8 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 15.5 | 17.1 | - |  |
| Bypass |  | 20 | 21 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -3 | -0.5 | - |  |
| Bypass |  | 24.5 | 25.7 | - |  |
| Out Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | 6.7 | 8 | - |  |
| In Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | -11 | -9.6 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.46 | 1.75 |  |
| Bypass |  | - | 4.9 | 5.9 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 4.8 | 5.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.2 | - | k $\Omega$ |

Table 8. Typical 2140 MHz Evaluation Board Performance (continued) $\left(\mathrm{VCc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -10.5 | -7 |  |
| Bypass |  | - | -13.5 | -10 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 16.5 | 17.6 | - |  |
| Bypass |  | -5.7 | -4.7 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -24.7 | -23.7 |  |
| Bypass |  | - | -4.5 | -4 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -11 | -8 |  |
| Bypass |  | - | -20.8 | -10 |  |
| $\mathrm{R} 1=1.5 \mathrm{~K} \Omega$ (Refer to Figure 9) |  |  |  |  |  |
| Frequency | f | - | 2140 | - | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 16.4 | 17.4 | - |  |
| Bypass |  | -5.8 | -4.8 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 16 | 18 | - |  |
| Bypass |  | 19.5 | 21 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -2 | 0.9 | - |  |
| Bypass |  | 24.7 | 25.7 | - |  |
| Out Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | 7 | 8 | - |  |
| In Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | -10.3 | $-9.3$ | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.46 | 1.75 |  |
| Bypass |  | - | 4.7 | 5.3 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 3.8 | 4.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.5 | - | $\mathrm{k} \Omega$ |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -9.6 | -8 |  |
| Bypass |  | - | -13 | -9 |  |

Table 8. Typical 2140 MHz Evaluation Board Performance (continued)

$$
\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}\right)
$$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 16.5 | 17.4 | - |  |
| Bypass |  | -5.4 | -4.7 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -24 | 21.6 |  |
| Bypass |  | - | -4.6 | 4.1 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -10.6 | -8 |  |
| Bypass |  | - | -21 | -10 |  |

### 3.4 2400 MHz Application

This application was designed to provide $\mathrm{NF}=1.5 \mathrm{~dB}, \mathrm{~S} 21$ gain $>16 \mathrm{~dB}$, OIP3 of 17.5 dBm with return losses better than -9 dB at 2400 MHz . Typical performance that can be expected from this circuit at 2.7 V is listed in Table 9. Two values of bias resistor R1 are shown to demonstrate performance for different IP3 and Icc requirements. Resistor R3 is used to de-Q output inductor L2 and adjust gain and return losses. Lowering the value of R3 lowers gain and improves return losses.

Figure 9 is the 2400 MHz application schematic with package pinouts and the circuit component topology.


Figure 10. 2400 MHz Application Schematic

## Application Information

Table 9 shows the electrical characteristics for the 2400 MHz evaluation board.
Table 9. Typical 2400 MHz Evaluation Board Performance
$\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| R1=1.2 $\mathrm{K} \Omega$ (Refer to Figure 10) |  |  |  |  |  |
| Frequency | f |  | 2400 |  | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 15 | 16 | - |  |
| Bypass |  | -5.5 | -5 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 16 | 17.5 | - |  |
| Bypass |  | 18.5 | 20 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -0.2 | 1.3 | - |  |
| Bypass |  | 24 | 25.3 | - |  |
| Out Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | 7 | 8.1 | - |  |
| In Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | -9 | -8 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.51 | 1.8 |  |
| Bypass |  | - | 5.2 | 5.8 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 4.8 | 5.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.2 | - | k $\Omega$ |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -12.5 | -9 |  |
| Bypass |  | - | -14 | -10 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 14.7 | 15.7 | - |  |
| Bypass |  | -5.4 | -5 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -23.6 | -22.6 |  |
| Bypass |  | - | -5.5 | -4.5 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -12 | -9 |  |
| Bypass |  | - | -22.5 | -20 |  |

Table 9. Typical 2400 MHz Evaluation Board Performance (continued)

$$
\left(\mathrm{Vcc}=2.75 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}\right)
$$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| R1=1.5 $\mathrm{K} \Omega$ (Refer to Figure 10) |  |  |  |  |  |
| Frequency | f | - | 2400 | - | MHz |
| RF Gain | G |  |  |  | dB |
| High Gain |  | 14.9 | 15.9 | - |  |
| Bypass |  | -6 | -5 | - |  |
| Output Third Order Intercept Point | OIP3 |  |  |  | dBm |
| High Gain |  | 16 | 18 | - |  |
| Bypass |  | 19.2 | 20.4 | - |  |
| Input Third Order Intercept Point | IIP3 |  |  |  | dBm |
| High Gain |  | -0.2 | 2 | - |  |
| Bypass |  | 24.3 | 25.3 | - |  |
| Out Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | 7 | 7.9 | - |  |
| In Ref P1dB | P1dB |  |  |  | dBm |
| High Gain |  | -8.8 | -7.8 | - |  |
| Noise Figure | NF |  |  |  | dB |
| High Gain |  | - | 1.52 | 1.8 |  |
| Bypass |  | - | 5.2 | 6 |  |
| Current Draw | Icc |  |  |  |  |
| High Gain |  | - | 3.8 | 4.8 | mA |
| Bypass |  | - | 4 | 20 | $\mu \mathrm{A}$ |
| Rbias R1 Value | - | - | 1.5 | - | k ת |
| Input Return Loss | S11 |  |  |  | dB |
| High Gain |  | - | -10.7 | -9 |  |
| Bypass |  | - | -14.5 | -12 |  |
| Gain | S21 |  |  |  | dB |
| High Gain |  | 14.4 | 15.4 | - |  |
| Bypass |  | -6 | -5.1 | - |  |
| Reverse Isolation | S12 |  |  |  | dB |
| High Gain |  | - | -23.3 | -22 |  |
| Bypass |  | - | -5.5 | -4.5 |  |
| Output Return Loss | S22 |  |  |  | dB |
| High Gain |  | - | -11.3 | -8.5 |  |
| Bypass |  | - | -21.9 | -15 |  |

## Printed Circuit and Bill of Materials

## 4 Printed Circuit and Bill of Materials

Figure 11 is the drawing of the printed circuit board. Figure 13 is the drawing of the evaluation board used for each of the application frequency designs described in Section 3, "Application Information." These drawings show the boards with the circuit matching components placed and identified.


Note: Dimensions are in inches and [mm].
Soldering Note: The center flag under the part must be soldered to board.
Figure 11. Printed Circuit Board
Figure 11 is a picture of a typical assembled evaluation board similar to the ones in the evaluation kits.


Figure 12. Typical Assembled Evaluation Board with SMA Connectors


Figure 13. 1575-, 1960-, 2140-, 2400 MHz Application Board
The bill of materials for each of the application frequency circuit boards is listed in Table 10. The value, case size, manufacturer and circuit function of each component are shown.

Table 10. Bill of Materials for the Application Circuit Boards

| Component | Value | Case | Manufacturer | Comments |
| :---: | :---: | :---: | :---: | :--- |
| 1575 MHz Application Circuit (see Figure 7) |  |  |  |  |
| C1 | 22 pF | 402 | Murata | DC block, input match |
| C2 | 1 pF | 402 | Murata | DC block, output match |
| C3 | 33 pF | 402 | Murata | RF bypass |
| C4 | $0.1 \mathrm{\mu F}$ | 402 | Murata | Low frequency bypass |
| L1 | 4.7 nH | 402 | Murata | Input match |
| L2 | 5.1 nH | 402 | Murata | Output match, bias decouple |
| L3 | 270 nH | 402 | Murata | Bias couple to logic |
| R1 | $1.2 \mathrm{k} \Omega$ | 402 | KOA | Bias set point |
| R2 | $10 \Omega$ | 402 | KOA | Stability |
| R3 | $150 \Omega$ | 402 | KOA | L2 de-Q, gain adjust |
| 1900 MHz Application Circuit (see Figure 8) |  |  |  |  |
| C1 | 2.4 pF | 402 | Murata | Input match |
| C2 | 0.9 pF | 402 | Murata | Output match |
| C3 | 33 pF | 402 | Murata | RF bypass |
| C4 | $.01 \mu \mathrm{~F}$ | 805 | Murata | Low frequency bypass |
| L1 | 5.1 nH | 402 | Murata | Input match |
| L2 | 3.3 nH | 402 | Murata | Output match |
| L3 | 270 nH | 402 | Murata | Bias couple to logic |
| R1 | $1.2 \mathrm{k} \Omega$ | 402 | KOA | LNA bias |
| R2 | $15 \Omega$ | 402 | KOA | Stability |
| R3 | 620 | 402 | KOA | De-Q L2, adjust gain, RLs |

Table 10. Bill of Materials for the Application Circuit Boards (continued)

| Component | Value | Case | Manufacturer | Comments |
| :---: | :---: | :---: | :---: | :--- |
| $\mathbf{2 1 4 0 ~ M H z ~ A p p l i c a t i o n ~ C i r c u i t ~ ( s e e ~ F i g u r e ~ 9 ) ~}$ |  |  |  |  |
| C1 | 2.4 pF | 402 | Murata | Input match |
| C2 | 0.9 pF | 402 | Murata | Output match |
| C3 | 33 pF | 402 | Murata | RF bypass |
| C4 | $.01 \mu \mathrm{~F}$ | 805 | Murata | Low frequency bypass |
| L1 | 4.7 nH | 402 | Murata | Input match |
| L2 | 2.7 | 402 | Murata | Output match |
| L3 | 270 nH | 402 | Murata | Bias couple to logic |
| R1 | $1.2 \mathrm{k} \Omega$ | 402 | KOA | LNA bias |
| R2 | $10 \Omega$ | 402 | KOA | Stability |
| R3 | 620 | 402 | KOA | De-Q L2, adjust gain, RLs |
| $\mathbf{2 4 0 0 ~ M H z ~ A p p l i c a t i o n ~ C i r c u i t ~ ( s e e ~ F i g u r e ~ 1 0 ) ~}$ |  |  |  |  |
| C1 | 2.4 pF | 402 | Murata | Input match |
| C2 | 0.9 pF | 402 | Murata | Output match |
| C3 | 33 pF | 402 | Murata | RF bypass |
| C4 | $.01 \mu \mathrm{~F}$ | 805 | Murata | Low frequency bypass |
| L1 | 3.6 nH | 402 | Murata | Input match |
| L2 | 2 | 402 | Murata | Output match |
| L3 | 270 nH | 402 | Murata | Bias couple to logic |
| R1 | $1.2 \mathrm{k} \Omega$ | 402 | KOA | LNA bias |
| R2 | $10 \Omega$ | 402 | KOA | Stability |
| R3 | 620 | 402 | KOA | De-Q L2, adjust gain, RLs |

## 5 Scattering and Noise Parameters

Table 11 through Table 14 list the S parameters for the packaged part in a $50 \Omega$ system for each of the modes of operation and for two values of the external bias resistor.

Table 11. Scattering Parameters, Active Mode, Rbias=1.2k $\Omega$
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| $\mathbf{f}(\mathbf{M H z})$ | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | ---: | ---: | ---: | ---: | ---: | ---: | ---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1000 | 0.712 | -19.7 | 10.508 | 145.3 | 0.027 | 94.1 | 0.913 | 9.6 |
| 1050 | 0.696 | -20.3 | 10.318 | 144.3 | 0.029 | 94.3 | 0.904 | 10.0 |
| 1100 | 0.679 | -21.2 | 10.132 | 143.1 | 0.030 | 94.8 | 0.896 | 10.5 |
| 1150 | 0.663 | -21.7 | 9.947 | 142.2 | 0.031 | 94.8 | 0.886 | 10.7 |
| 1200 | 0.651 | -21.9 | 9.742 | 141.0 | 0.033 | 95.1 | 0.875 | 10.8 |
| 1250 | 0.634 | -22.2 | 9.552 | 140.2 | 0.034 | 95.6 | 0.870 | 11.0 |
| 1300 | 0.619 | -22.4 | 9.413 | 139.3 | 0.035 | 96.4 | 0.861 | 11.2 |

Table 11. Scattering Parameters, Active Mode, Rbias=1.2k (continued)
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| f (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1350 | 0.607 | -22.9 | 9.242 | 138.3 | 0.036 | 97.3 | 0.854 | 11.5 |
| 1400 | 0.597 | -23.3 | 9.069 | 138.0 | 0.038 | 98.5 | 0.851 | 11.6 |
| 1450 | 0.587 | -23.6 | 8.977 | 137.0 | 0.040 | 99.3 | 0.847 | 11.4 |
| 1500 | 0.576 | -23.9 | 8.813 | 136.2 | 0.042 | 100.3 | 0.845 | 11.1 |
| 1550 | 0.571 | -24.4 | 8.806 | 135.9 | 0.044 | 101.5 | 0.846 | 10.2 |
| 1600 | 0.571 | -26.2 | 8.693 | 134.7 | 0.049 | 100.1 | 0.840 | 8.2 |
| 1650 | 0.556 | -28.2 | 8.583 | 133.0 | 0.050 | 97.4 | 0.802 | 7.2 |
| 1700 | 0.538 | -29.7 | 8.420 | 131.8 | 0.051 | 96.5 | 0.779 | 7.4 |
| 1750 | 0.519 | -31.3 | 8.284 | 130.8 | 0.052 | 96.4 | 0.764 | 7.2 |
| 1800 | 0.505 | -33.5 | 8.129 | 129.5 | 0.054 | 96.1 | 0.751 | 6.8 |
| 1850 | 0.486 | -35.7 | 8.009 | 128.3 | 0.057 | 95.2 | 0.737 | 5.6 |
| 1900 | 0.448 | -37.5 | 7.735 | 126.4 | 0.058 | 91.7 | 0.700 | 5.2 |
| 1950 | 0.435 | -37.8 | 7.564 | 126.2 | 0.058 | 92.2 | 0.688 | 5.5 |
| 2000 | 0.415 | -41.7 | 7.421 | 124.4 | 0.061 | 90.4 | 0.662 | 4.1 |
| 2050 | 0.376 | -45.4 | 7.155 | 122.5 | 0.063 | 86.6 | 0.618 | 3.7 |
| 2100 | 0.313 | -44.8 | 6.708 | 121.6 | 0.059 | 80.1 | 0.569 | 6.2 |
| 2150 | 0.28 | -37.0 | 6.321 | 121.8 | 0.052 | 79.7 | 0.541 | 11.7 |
| 2200 | 0.251 | -29.5 | 5.956 | 125.2 | 0.044 | 78.1 | 0.561 | 18.1 |
| 2250 | 0.309 | -16.2 | 6.073 | 130.1 | 0.037 | 100.5 | 0.648 | 20.3 |
| 2300 | 0.367 | -24.7 | 6.554 | 129.3 | 0.050 | 110.1 | 0.694 | 14.8 |
| 2350 | 0.364 | -30.5 | 6.756 | 126.9 | 0.058 | 108.1 | 0.678 | 9.3 |
| 2400 | 0.351 | -35.0 | 6.542 | 124.4 | 0.062 | 104.0 | 0.648 | 8.3 |
| 2450 | 0.338 | -37.9 | 6.459 | 122.8 | 0.065 | 102.4 | 0.627 | 7.8 |
| 2500 | 0.323 | -40.5 | 6.304 | 121.6 | 0.066 | 100.3 | 0.613 | 8.1 |
| 2550 | 0.319 | -41.4 | 6.168 | 120.6 | 0.067 | 100.7 | 0.608 | 8.1 |
| 2600 | 0.308 | -43.6 | 6.047 | 119.6 | 0.068 | 99.4 | 0.606 | 7.1 |

Table 12. Scattering Parameters, Active Mode, Rbias=1.5k $\Omega$
$\left(\mathrm{Vcc}=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega\right.$ system $)$

| $\mathbf{f}(\mathbf{M H z})$ | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | ---: | ---: | ---: | ---: | ---: | ---: | ---: | ---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1000 | 0.754 | -17.9 | 9.171 | 150.9 | 0.028 | 94.9 | 0.941 | 10.7 |
| 1050 | 0.739 | -18.6 | 9.055 | 149.8 | 0.029 | 95.2 | 0.933 | 11.1 |
| 1100 | 0.721 | -19.4 | 8.902 | 148.7 | 0.031 | 95.0 | 0.927 | 11.7 |
| 1150 | 0.709 | -19.9 | 8.774 | 147.9 | 0.032 | 95.4 | 0.918 | 11.8 |
| 1200 | 0.698 | -20.3 | 8.629 | 146.8 | 0.033 | 95.6 | 0.910 | 12.0 |
| 1250 | 0.682 | -20.6 | 8.517 | 146.2 | 0.035 | 96.3 | 0.907 | 12.2 |

Table 12. Scattering Parameters, Active Mode, Rbias $=1.5 \mathrm{k} \Omega$ (continued)
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| f (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1300 | 0.667 | -21.2 | 8.444 | 145.1 | 0.036 | 96.3 | 0.897 | 12.2 |
| 1350 | 0.654 | -21.9 | 8.318 | 144.0 | 0.037 | 96.4 | 0.888 | 12.4 |
| 1400 | 0.640 | -22.5 | 8.150 | 143.8 | 0.039 | 97.1 | 0.884 | 12.6 |
| 1450 | 0.625 | -22.8 | 8.093 | 142.6 | 0.040 | 97.3 | 0.876 | 12.6 |
| 1500 | 0.611 | -23.0 | 7.908 | 141.9 | 0.041 | 97.6 | 0.871 | 12.6 |
| 1550 | 0.595 | -23.1 | 7.910 | 141.3 | 0.043 | 98.2 | 0.863 | 12.2 |
| 1600 | 0.591 | -23.1 | 7.668 | 140.8 | 0.044 | 98.5 | 0.861 | 11.8 |
| 1650 | 0.586 | -24.0 | 7.619 | 139.9 | 0.046 | 99.0 | 0.841 | 11.5 |
| 1700 | 0.577 | -25.1 | 7.505 | 139.2 | 0.048 | 99.0 | 0.829 | 11.8 |
| 1750 | 0.560 | -26.7 | 7.410 | 138.5 | 0.049 | 99.1 | 0.821 | 11.9 |
| 1800 | 0.548 | -28.0 | 7.283 | 137.6 | 0.050 | 99.4 | 0.813 | 11.7 |
| 1850 | 0.528 | -28.8 | 7.154 | 136.9 | 0.052 | 99.6 | 0.807 | 11.5 |
| 1900 | 0.513 | -28.8 | 7.006 | 136.3 | 0.053 | 98.7 | 0.794 | 11.4 |
| 1950 | 0.509 | -29.0 | 6.929 | 136.3 | 0.054 | 99.8 | 0.789 | 11.5 |
| 2000 | 0.500 | -31.2 | 6.861 | 135.6 | 0.056 | 100.1 | 0.781 | 11.1 |
| 2050 | 0.489 | -32.4 | 6.832 | 134.8 | 0.058 | 101.1 | 0.773 | 10.7 |
| 2100 | 0.475 | -33.9 | 6.707 | 134.5 | 0.060 | 100.5 | 0.770 | 10.2 |
| 2150 | 0.467 | -34.2 | 6.660 | 133.1 | 0.062 | 101.1 | 0.750 | 9.6 |
| 2200 | 0.454 | -37.8 | 6.588 | 133.3 | 0.063 | 99.6 | 0.745 | 9.2 |
| 2250 | 0.436 | -39.4 | 6.538 | 132.1 | 0.065 | 100.1 | 0.730 | 8.6 |
| 2300 | 0.409 | -41.7 | 6.508 | 130.5 | 0.066 | 98.0 | 0.714 | 8.4 |
| 2350 | 0.390 | -40.9 | 6.467 | 129.7 | 0.067 | 98.2 | 0.693 | 7.3 |
| 2400 | 0.378 | -41.5 | 6.181 | 128.3 | 0.067 | 97.2 | 0.671 | 8.6 |
| 2450 | 0.369 | -42.2 | 6.079 | 127.5 | 0.068 | 97.5 | 0.659 | 9.7 |
| 2500 | 0.359 | -43.2 | 5.945 | 126.8 | 0.068 | 97.6 | 0.651 | 10.7 |
| 2550 | 0.356 | -44.0 | 5.825 | 126.3 | 0.069 | 97.8 | 0.652 | 11.4 |
| 2600 | 0.348 | -44.7 | 5.680 | 125.7 | 0.069 | 98.1 | 0.652 | 11.9 |

Table 13. Scattering Parameters, Bypass Mode, Rbias=1.2k $\Omega$ and $1.5 \mathrm{k} \Omega$
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system $)$

| $\mathbf{f}$ (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | :---: | ---: | ---: | ---: | ---: | ---: | ---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1000 | 0.356 | -25.9 | 0.658 | 25.8 | 0.646 | 25.2 | 0.402 | -12.4 |
| 1050 | 0.340 | -24.6 | 0.663 | 24.9 | 0.651 | 24.3 | 0.387 | -11.3 |
| 1100 | 0.327 | -23.0 | 0.667 | 24.0 | 0.655 | 23.5 | 0.373 | -9.9 |
| 1150 | 0.312 | -21.4 | 0.671 | 23.3 | 0.659 | 22.7 | 0.359 | -8.2 |
| 1200 | 0.298 | -20.3 | 0.674 | 22.6 | 0.662 | 22.0 | 0.347 | -6.5 |

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Table 13. Scattering Parameters, Bypass Mode, Rbias=1.2k $\Omega$ and $1.5 \mathrm{k} \Omega$ (continued)
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| f (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1250 | 0.288 | -18.7 | 0.677 | 21.8 | 0.665 | 21.4 | 0.336 | -4.7 |
| 1300 | 0.275 | -16.7 | 0.678 | 21.2 | 0.667 | 20.7 | 0.326 | -3.4 |
| 1350 | 0.263 | -14.8 | 0.679 | 20.6 | 0.668 | 20.1 | 0.318 | -1.9 |
| 1400 | 0.253 | -12.6 | 0.678 | 20.0 | 0.667 | 19.6 | 0.311 | -0.7 |
| 1450 | 0.248 | -10.0 | 0.675 | 19.9 | 0.664 | 19.5 | 0.306 | -0.3 |
| 1500 | 0.250 | -9.6 | 0.680 | 20.0 | 0.669 | 19.6 | 0.289 | 0.9 |
| 1550 | 0.244 | -10.4 | 0.687 | 19.5 | 0.676 | 19.1 | 0.279 | 2.1 |
| 1600 | 0.235 | -10.0 | 0.689 | 18.9 | 0.678 | 18.5 | 0.272 | 3.7 |
| 1650 | 0.226 | -10.2 | 0.690 | 18.5 | 0.680 | 18.0 | 0.267 | 4.9 |
| 1700 | 0.220 | -9.5 | 0.690 | 17.8 | 0.680 | 17.3 | 0.260 | 6.3 |
| 1750 | 0.211 | -8.5 | 0.689 | 17.4 | 0.679 | 17.0 | 0.253 | 6.9 |
| 1800 | 0.197 | -6.2 | 0.685 | 16.9 | 0.675 | 16.4 | 0.245 | 6.8 |
| 1850 | 0.199 | -1.7 | 0.682 | 17.3 | 0.673 | 16.9 | 0.235 | 7.3 |
| 1900 | 0.202 | -3.2 | 0.688 | 17.0 | 0.679 | 16.6 | 0.229 | 8.5 |
| 1950 | 0.194 | -5.0 | 0.688 | 16.5 | 0.678 | 16.1 | 0.223 | 9.4 |
| 2000 | 0.186 | -4.4 | 0.687 | 16.1 | 0.677 | 15.8 | 0.213 | 8.4 |
| 2050 | 0.182 | -3.6 | 0.682 | 16.2 | 0.673 | 15.8 | 0.204 | 8.1 |
| 2100 | 0.180 | -4.2 | 0.686 | 16.3 | 0.676 | 15.9 | 0.198 | 9.5 |
| 2150 | 0.185 | -4.3 | 0.689 | 16.2 | 0.680 | 15.9 | 0.192 | 11.2 |
| 2200 | 0.185 | -5.5 | 0.695 | 15.7 | 0.685 | 15.4 | 0.186 | 10.4 |
| 2250 | 0.187 | -8.3 | 0.695 | 15.2 | 0.685 | 14.9 | 0.185 | 9.3 |
| 2300 | 0.186 | -10.1 | 0.697 | 14.6 | 0.688 | 14.3 | 0.178 | 7.5 |
| 2350 | 0.185 | -12.0 | 0.694 | 14.2 | 0.685 | 13.8 | 0.173 | 7.0 |
| 2400 | 0.181 | -14.1 | 0.696 | 13.7 | 0.686 | 13.4 | 0.168 | 4.1 |
| 2450 | 0.178 | -16.8 | 0.695 | 13.1 | 0.681 | 12.5 | 0.159 | 2.0 |
| 2500 | 0.177 | -19.8 | 0.694 | 12.5 | 0.680 | 11.9 | 0.155 | -1.7 |
| 2550 | 0.174 | -23.6 | 0.691 | 11.8 | 0.677 | 11.2 | 0.150 | -5.6 |
| 2600 | 0.171 | -27.4 | 0.686 | 11.2 | 0.673 | 10.6 | 0.143 | -9.1 |

Table 14. Scattering Parameters, Standby Mode, Rbias=1.2k $\Omega$ and $1.5 \mathrm{k} \Omega$
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| $\mathbf{f}(\mathbf{M H z})$ | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | ---: | ---: | ---: | ---: | ---: | ---: | ---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1000 | 0.939 | 2.1 | 0.031 | 104.0 | 0.031 | 103.1 | 0.991 | 12.9 |
| 1050 | 0.935 | 2.2 | 0.033 | 104.4 | 0.033 | 103.8 | 0.990 | 13.3 |
| 1100 | 0.934 | 2.5 | 0.035 | 104.8 | 0.034 | 104.2 | 0.988 | 13.5 |
| 1150 | 0.931 | 2.7 | 0.037 | 105.2 | 0.036 | 104.4 | 0.986 | 14.0 |

Table 14. Scattering Parameters, Standby Mode, Rbias=1.2k $\Omega$ and $1.5 \mathrm{k} \Omega$ (continued)
(Vcc $=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system)

| f (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Mag | Ang | Mag | Ang | Mag | Ang | Mag | Ang |
| 1200 | 0.926 | 2.7 | 0.039 | 105.4 | 0.038 | 104.7 | 0.985 | 14.5 |
| 1250 | 0.924 | 2.6 | 0.041 | 105.8 | 0.040 | 105.2 | 0.982 | 15.0 |
| 1300 | 0.920 | 2.8 | 0.043 | 105.8 | 0.042 | 105.3 | 0.978 | 15.0 |
| 1350 | 0.914 | 2.9 | 0.045 | 106.1 | 0.044 | 105.5 | 0.977 | 15.2 |
| 1400 | 0.906 | 2.9 | 0.047 | 106.4 | 0.046 | 105.9 | 0.974 | 15.5 |
| 1450 | 0.896 | 3.3 | 0.048 | 106.9 | 0.048 | 106.2 | 0.973 | 15.7 |
| 1500 | 0.901 | 3.7 | 0.051 | 108.4 | 0.050 | 107.8 | 0.969 | 16.0 |
| 1550 | 0.907 | 3.3 | 0.054 | 108.6 | 0.053 | 107.9 | 0.965 | 15.9 |
| 1600 | 0.904 | 2.9 | 0.056 | 108.4 | 0.056 | 108.0 | 0.964 | 15.9 |
| 1650 | 0.900 | 2.4 | 0.059 | 108.8 | 0.058 | 108.3 | 0.959 | 16.1 |
| 1700 | 0.896 | 1.7 | 0.061 | 109.2 | 0.061 | 108.6 | 0.957 | 16.2 |
| 1750 | 0.886 | 1.3 | 0.064 | 109.7 | 0.063 | 109.2 | 0.954 | 16.1 |
| 1800 | 0.871 | 1.1 | 0.068 | 111.0 | 0.067 | 110.4 | 0.948 | 15.7 |
| 1850 | 0.859 | 2.3 | 0.074 | 109.8 | 0.073 | 109.4 | 0.946 | 15.7 |
| 1900 | 0.871 | 2.1 | 0.075 | 108.1 | 0.074 | 107.5 | 0.941 | 15.4 |
| 1950 | 0.866 | 1.0 | 0.078 | 109.2 | 0.076 | 108.7 | 0.935 | 15.3 |
| 2000 | 0.855 | 0.4 | 0.081 | 109.1 | 0.080 | 108.9 | 0.929 | 15.0 |
| 2050 | 0.843 | 0.5 | 0.086 | 110.1 | 0.085 | 109.8 | 0.923 | 14.3 |
| 2100 | 0.844 | 0.3 | 0.093 | 108.8 | 0.092 | 108.4 | 0.920 | 14.2 |
| 2150 | 0.848 | -0.2 | 0.100 | 106.5 | 0.099 | 106.0 | 0.916 | 14.0 |
| 2200 | 0.853 | -0.9 | 0.103 | 103.2 | 0.101 | 102.8 | 0.911 | 13.2 |
| 2250 | 0.853 | -2.1 | 0.105 | 101.6 | 0.104 | 101.0 | 0.907 | 12.4 |
| 2300 | 0.850 | -3.1 | 0.106 | 99.8 | 0.105 | 99.4 | 0.901 | 11.6 |
| 2350 | 0.844 | -3.9 | 0.110 | 99.2 | 0.109 | 98.7 | 0.891 | 10.8 |
| 2400 | 0.838 | -5.1 | 0.113 | 97.0 | 0.111 | 96.4 | 0.887 | 9.9 |
| 2450 | 0.829 | -6.5 | 0.116 | 96.2 | 0.114 | 95.2 | 0.877 | 8.9 |
| 2500 | 0.820 | -7.9 | 0.119 | 93.5 | 0.117 | 92.6 | 0.867 | 7.6 |
| 2550 | 0.807 | -9.4 | 0.122 | 91.3 | 0.120 | 90.6 | 0.858 | 6.1 |
| 2600 | 0.791 | -11.2 | 0.125 | 88.1 | 0.122 | 87.4 | 0.840 | 4.9 |

Table 15 provides the active mode noise parameters when the bias resistor is $1.2 \mathrm{k} \Omega$.
Table 15. Active Mode Noise Parameters, Rbias=1.2k $\Omega$
(Vcc = 2.75V, $250 \mathrm{C}, 50 \Omega$ system, $\mathrm{Icc}=4.6 \mathrm{~mA}$ )

| $\begin{gathered} \text { Freq } \\ \text { (MHz) } \end{gathered}$ | Fmin (dB) | Gamma Opt |  | Rn | $\begin{gathered} \mathrm{Ga} \\ \text { (dB) } \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Mag | Angle |  |  |
| 1000 | 0.91 | 0.329 | -8.8 | 14.0 | 27.42 |
| 1200 | 0.92 | 7.000 | -7.3 | 13.5 | 25.09 |

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Table 15. Active Mode Noise Parameters, Rbias $=1.2 \mathrm{k} \Omega$ (continued)
$(\mathrm{Vcc}=2.75 \mathrm{~V}, 250 \mathrm{C}, 50 \Omega$ system, $\mathrm{Icc}=4.6 \mathrm{~mA})$

| $\begin{gathered} \text { Freq } \\ (\mathrm{MHz}) \end{gathered}$ | Fmin <br> (dB) | Gamma Opt |  | Rn | $\begin{gathered} \mathrm{Ga} \\ (\mathrm{~dB}) \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Mag | Angle |  |  |
| 1500 | 0.96 | 0.279 | -12.3 | 12.5 | 22.83 |
| 1700 | 0.99 | 0.244 | -17.2 | 12 | 21.43 |
| 1900 | 1.02 | 0.206 | -20.8 | 11.5 | 20.15 |
| 2000 | 1.04 | 0.186 | -21.5 | 11.5 | 19.57 |
| 2100 | 1.06 | 0.167 | -20.9 | 11.0 | 19.04 |
| 2400 | 1.13 | 0.114 | -9.6 | 11.0 | 17.74 |
| 2500 | 1.15 | 0.100 | -1.6 | 10.5 | 17.43 |
| 2600 | 1.18 | 0.087 | 8.8 | 10.5 | 17.18 |

Table 16 provides the active mode noise parameters when the bias resistor is $1.5 \mathrm{k} \Omega$.
Table 16. Active Mode Noise Parameters, Rbias=1.5k $\Omega$
( $\mathrm{Vcc}=2.75 \mathrm{~V}, 25^{\circ} \mathrm{C}, 50 \Omega$ system, $\mathrm{Icc}=3.3 \mathrm{~mA}$ )

| $\begin{gathered} \text { Freq } \\ (\mathrm{MHz}) \end{gathered}$ | Fmin <br> (dB) | Gamma Opt |  | Rn | $\begin{gathered} \mathrm{Ga} \\ \text { (dB) } \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Mag | Angle |  |  |
| 1000 | 0.92 | 0.358 | -8.3 | 14.5 | 26.42 |
| 1200 | 0.93 | 0.344 | -8.7 | 14.0 | 24.84 |
| 1500 | 0.97 | 0.306 | -12.5 | 13.5 | 22.78 |
| 1700 | 1.00 | 0.273 | -15.2 | 13.0 | 21.59 |
| 1900 | 1.04 | 0.237 | -16.6 | 12.0 | 20.53 |
| 2000 | 1.06 | 0.218 | -16.4 | 12.0 | 20.03 |
| 2100 | 1.08 | 0.199 | -15.4 | 12.0 | 19.57 |
| 2400 | 1.16 | 0.143 | -5.5 | 11.5 | 18.30 |
| 2500 | 1.19 | 0.127 | 0.6 | 11.5 | 17.91 |
| 2600 | 1.23 | 0.111 | 8.3 | 11.5 | 17.53 |

## Scattering and Noise Parameters

Figure 14 through Figure 21 are the constant noise figure and gain circles with input and output stability regions shown on Smith charts. Gamma opt, noise resistance and stability at the frequency are shown for two values of the external bias resistor at 1600-, 1950-, $2150-$ and 2400 MHz .


Figure 14. Constant Noise Figure and Gain Circles, 1600 MHz , Rbias=1.2 k $\Omega$


Figure 15. Constant Noise Figure and Gain Circles, 1600 MHz , Rbias=1.5k $\Omega$


Figure 16. Constant Noise Figure and Gain Circles, 1960 MHz , Rbias=1.2 k $\Omega$


Figure 17. Constant Noise Figure and Gain Circles, 1960 MHz , Rbias=1.5k $\Omega$


Figure 18. Constant Noise Figure and Gain Circles, 2140 MHz , Rbias=1.2 k $\Omega$


Figure 19. Constant Noise Figure and Gain Circles, 2140 MHz , Rbias=1.5k $\Omega$


Figure 20. Constant Noise Figure and Gain Circles, $\mathbf{2 4 0 0} \mathrm{MHz}$, Rbias=1.2 k $\Omega$


Figure 21. Constant Noise Figure and Gain Circles, 2400 MHz , Rbias=1.5k $\Omega$

## Packaging

## 6 Packaging

Figure 22 and Figure 22 are the package drawings with dimensions for the MLPD-8, $2 \times 2 \times 0.6 \mathrm{~mm}$, package.


Figure 22. Outline Dimensions for MLPD-8


DETAIL G

```
NOTES:
1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. THIS IS NON JEDEC REGISTERED PACKAGE.
4. COPLANARITY APPLIES TO THE TERMINALS AND ALL OTHER BOTTOM SURFACE METALLIZATION.
5. THIS DIMENSION APPLIES TO METALLIZED TERMINAL AND IS MEASURE BETWEEN 0.15 AND 0.25
    FROM THE TERMINAL TIP. IF THE TERMINAL HAS THE OPTIONAL RADIUS ON THE OTHER END
    OF THE TERMINAL, THIS DIMENSION SHALL NOT BE MEASURED IN THE RADIUS AREA.
```

Figure 23. Package Details

## 7 Product Documentation

This data sheet is labeled as a particular type: Product Preview, Advance Information, or Technical Data. Definitions of these types are available at: http://www.freescale.com.

## 8 Revision History

Table 17 summarizes revisions to this document since the previous release (Rev. 1).
Table 17. Revision History

| Location | Revision |
| :--- | :--- |
| Throughout document | Changed package from MLF8 to MLPD-8 |
| Section 2, "Electrical Specifications | Complete revision |
| Section 3, "Application Information | Complete update to Application Information |
| Section 3.4, "2400 MHz Application | New 2400 MHz content. |
| Section 4, "Printed Circuit and Bill of Materials | Complete update to MLPD-8 package. |
| Section 5, "Scattering and Noise Parameters | Added section and all content. |

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